## WS7916S

## CMOS High Gain GPS LNA

## Descriptions

The WS7916S is a low noise amplifier (LNA) for GNSS receiver applications (including GPS, GLONASS, BeiDou and Galileo), available in a small 6-pin DFN package. The WS7916S requires only one external inductor for input matching.

The WS7916S is designed to achieve low power dissipation and good performance.

## Features

- Operating frequency: 1550 MHz to 1615 MHz
- Noise figure $=0.65 \mathrm{~dB}$
- Gain $=16.5 \mathrm{~dB}$
- Input 1 dB compression point $=-5.5 \mathrm{dBm}$
- Out-of-band input IP3 $=+8.0 \mathrm{dBm}$
- Supply voltage: 1.8 V to 3.1 V
- Integrated supply decoupling capacitor
- Digital On/Off switch (1.2 V logic high level)
- Supply current: 6.9 mA
- Power-down mode leakage current $<3 \mu \mathrm{~A}$
- One external matching inductor required
- RF output internally matched to 50 Ohm
- ESD protection: HBM $>2.0 \mathrm{kV}$ for all pins
- Package: 6-pin DFN, $1.5 \times 1.0 \times 0.55 \mathrm{~mm}^{3}$
- Process: CMOS


## Applications

- Cell phones
- Tablets
- Other RF front-end modules
http//:www.sh-willsemi.com


DFN1510-6L (Bottom view)


Pin configuration (Top view)


S = Device code

* $\quad=$ Month code (A~Z)

Marking (Top view)
Order information

| Device | Package | Shipping |
| :---: | :---: | :---: |
| WS7916S-6/TR | DFN1510-6L | 3000/Reel\&Tape |

## Pinning Information

| Pin | Description | Trans | sparent top view | Symbol view |
| :---: | :---: | :---: | :---: | :---: |
| 1 | GNDRF |  |  |  |
| 2 | GND |  |  |  |
| 3 | RFIN |  |  |  |
| 4 | VDD |  |  |  |
| 5 | EN |  |  |  |
| 6 | RFOUT |  |  |  |

## Application Information



| Symbol | Description | Footprint | Value | Supplier | Comment |
| :---: | :--- | :--- | :--- | :--- | :--- |
| U1 | WS7916S | $1.5 \times 1.0 \times 0.55 \mathrm{~mm}^{3}$ | $\mathrm{~N} / \mathrm{A}$ | Will-Semi | DUT |
| C1 | Capacitor | 0402 | 1 nF | Various | DC blocking |
| C2 | Capacitor | 0402 | 1 nF | Various | Supply decoupling |
| L1 | Inductor | 0402 | 10 nH | Murata LQW15 | Input matching |

## Quick Reference Data

Freq $=1575.42 \mathrm{MHz} ; \mathrm{V}_{\mathrm{CC}}=2.8 \mathrm{~V} ; \mathrm{V}_{\mathrm{EN}}>1.2 \mathrm{~V}$; Temp $=25^{\circ} \mathrm{C}$; input matched to $50 \Omega$ with a 10 nH inductor. The condition is applied unless otherwise specified.

| Symbol | Parameter | Condition | Min | Typ | Max | Unit |
| :---: | :--- | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{Cc}}$ | Supply voltage |  | 1.8 | 2.8 | 3.1 | V |
| $\mathrm{I}_{\mathrm{CC}}$ | Supply current |  |  | 6.9 |  | mA |
| $\mathrm{G}_{\mathrm{p}}$ | Power gain |  |  | 16.5 |  | dB |
| NF | Noise figure |  |  | 0.65 |  | dB |
| $\mathrm{IP}_{1 \mathrm{~dB}}$ | Input power at 1 dB gain compression |  |  | -5.5 |  | dBm |
| $\mathrm{II}_{3}$ | Input third-order intercept point |  |  | +8.0 |  | dBm |

## Recommended Operating Conditions

| Symbol | Parameter | Condition | Min | Typ | Max | Unit |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage |  | 1.8 |  | 3.1 | V |
| Temp | Ambient temperature |  | -40 | +25 | +85 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{V}_{\mathrm{EN}}$ | Input voltage on pin $6(\mathrm{EN})$ | OFF state |  | 0 | 0.4 | V |
|  |  | ON state | 1.2 | $\mathrm{~V}_{\mathrm{CC}}$ |  | V |

## Absolute Maximum Ratings

Maximum ratings are absolute ratings, exceeding only one of these values may cause irreversible damage to the integrated circuit.

| Symbol | Parameter | Condition | Min | Max | Unit |
| :---: | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {CC }}$ | Supply voltage |  | -0.3 | 3.1 | V |
| $\mathrm{~V}_{\text {EN }}$ | Input voltage on pin EN |  | -0.3 | 3.1 | V |
| $\mathrm{~V}_{\text {RFIN }}$ | Input voltage on pin RFIN |  | -0.3 | 3.1 | V |
| $\mathrm{~V}_{\text {RFOUT }}$ | Input voltage on pin RFOUT |  | -0.3 | 3.1 | V |
| $\mathrm{P}_{\text {in }}$ | RF input power |  |  | 0 | dBm |
| $\mathrm{T}_{\text {STG }}$ | Storage temperature |  | -65 | +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{J}$ | Junction temperature |  |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{V}_{\text {ESD }}$ | ESD capability all pins | Human Body Model (HBM) |  | $\pm 2000$ | V |

## Electrical Characteristics

$1550 \mathrm{MHz} \leq \mathrm{f} \leq 1615 \mathrm{MHz} ; \mathrm{V}_{\mathrm{CC}}=2.8 \mathrm{~V} ; \mathrm{V}_{\mathrm{EN}}>1.2 \mathrm{~V}$; Temp $=25^{\circ} \mathrm{C}$; input matched to $50 \Omega$ with a 10 nH inductor; The condition is applied unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{CC}}$ | Supply current | On state |  | 6.9 |  | mA |
|  |  | Off state |  |  | 3 | $\mu \mathrm{~A}$ |
| $\mathrm{G}_{\mathrm{p}}$ | Power gain | $\mathrm{f}=1575 \mathrm{MHz}$ |  | 16.5 |  | dB |
| $\mathrm{RL}_{\text {in }}$ | Input return loss | $\mathrm{f}=1575 \mathrm{MHz}$ |  | 8 |  | dB |
| $\mathrm{RL}_{\text {out }}$ | Output return loss | $\mathrm{f}=1575 \mathrm{MHz}$ |  | 13.0 |  | dB |
| ISL | Reverse isolation | $\mathrm{f}=1575 \mathrm{MHz}$ |  | 24.0 |  | dB |
| NF | Noise figure ${ }^{[1]}$ | $\mathrm{f}=1575 \mathrm{MHz}$ |  | 0.65 | dB |  |
| $\mathrm{IP}_{1 \mathrm{~dB}}$ | Input power at 1 dB gain <br> compression | $\mathrm{f}=1575 \mathrm{MHz}$ | -5.5 |  | dBm |  |
| $\mathrm{O}^{-I I P_{3}}$ | Out-of-band Input <br> third-order intercept point <br> $[2]$ |  | +8.0 |  | dBm |  |
| K | Rollett stability factor ${ }^{[3]}$ |  | 1 |  |  |  |
| $\mathrm{t}_{\mathrm{on}}$ | Turn-on time |  | 5 |  | $\mu \mathrm{~s}$ |  |
| $\mathrm{t}_{\text {off }}$ | Turn-off time |  | 5 |  | $\mu \mathrm{~s}$ |  |

$1550 \mathrm{MHz} \leq \mathrm{f} \leq 1615 \mathrm{MHz} ; \mathrm{V}_{\mathrm{CC}}=1.8 \mathrm{~V} ; \mathrm{V}_{\mathrm{EN}}>1.2 \mathrm{~V}$; Temp $=25^{\circ} \mathrm{C}$; input matched to $50 \Omega$ with a 10 nH inductor; The condition is applied unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{CC}}$ | Supply current | On state |  | 5 |  | mA |
|  |  | Off state |  |  | 3 | $\mu \mathrm{~A}$ |
| $\mathrm{G}_{\mathrm{p}}$ | Power gain | $\mathrm{f}=1575 \mathrm{MHz}$ |  | 15.5 |  | dB |
| $\mathrm{RL}_{\text {in }}$ | Input return loss | $\mathrm{f}=1575 \mathrm{MHz}$ |  | 7.5 |  | dB |
| $\mathrm{RL}_{\text {out }}$ | Output return loss | $\mathrm{f}=1575 \mathrm{MHz}$ |  | 13.0 |  | dB |
| ISL | Reverse isolation | $\mathrm{f}=1575 \mathrm{MHz}$ |  | 24.0 |  | dB |
| NF | Noise figure ${ }^{[1]}$ | $\mathrm{f}=1575 \mathrm{MHz}$ |  | 0.7 | dB |  |
| $\mathrm{IP}_{1 \mathrm{~dB}}$ | Input power at 1 dB gain <br> compression | $\mathrm{f}=1575 \mathrm{MHz}$ | -9.0 |  | dBm |  |
| $\mathrm{O}^{-I I P_{3}}$ | Out-of-band Input <br> third-order intercept point <br> $[2]$ |  | +8.0 |  | dBm |  |
| K | Rollett stability factor ${ }^{[3]}$ |  | 1 |  |  |  |
| $\mathrm{t}_{\mathrm{on}}$ | Turn-on time |  | 5 |  | $\mu \mathrm{~s}$ |  |
| $\mathrm{t}_{\text {off }}$ | Turn-off time |  | 5 |  | $\mu \mathrm{~s}$ |  |

[1] Including PCB loss (PCB loss: 0.05-0.1 dB @ 1.575 GHz)
[2] $f_{1}=1713 \mathrm{MHz}, f_{2}=1851 \mathrm{MHz}, P_{\text {in }}=-20 \mathrm{dBm}$
[3] 10M~20GHz

## Package Outline Dimensions

## DFN1510-6L



| Symbol | Dimensions In Millimeters |  |  |
| :---: | :---: | :---: | :---: |
|  | Min. | Typ. | Max. |
| A | 0.50 | N/A | 0.60 |
| A1 | 0.00 | 0.02 | 0.05 |
| A3 | 0.15 | $0.10 R E F$ | 0.25 |
| b | 0.90 | 0.20 | 1.10 |
| D | 1.40 | 1.00 | 1.60 |
| E | 0.40 | 1.50 | 0.60 |
| e |  | 0.50 |  |
| H | 0.30 | $0.10 R E F$ | 0.40 |
| L | 0.35 | 0.35 | 0.45 |
| L1 |  | 0.40 |  |

TAPE AND REEL INFORMATION
Reel Dimensions


Tape Dimensions


## Quadrant Assignments For PIN1 Orientation In Tape



User Direction of Feed

| RD | Reel Dimension | $\nabla$ 7inch $\ulcorner$ 13inch |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| W | Overall width of the carrier tape | $\checkmark 8 \mathrm{~mm}$ | $\ulcorner 12 \mathrm{~mm}$ | $\ulcorner 16 \mathrm{~mm}$ |  |
| P1 | Pitch between successive cavity centers | $\checkmark 2 \mathrm{~mm}$ | $\checkmark 4 \mathrm{~mm}$ | $\ulcorner 8 \mathrm{~mm}$ |  |
| Pin1 | Pin1 Quadrant | V Q1 | $\ulcorner\mathrm{Q} 2$ | $\ulcorner$ Q3 | $\ulcorner\mathrm{Q} 4$ |

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